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(54) **ELECTRONIC DEVICE WITH A CELL OF TRANSISTORS**

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(57)

ABSTRACT

An electronic device including a first active area of a first transistor, a first insulating region forming a first insulation of the first active area, a first insulating gate extending above the first active area and forming a second insulation of the first active area, and a first insulating gate contact coupled to the first insulating gate and positioned above both the first active area and the first insulating region, wherein the first insulating gate contact couples the first insulating gate to a power supply rail.

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